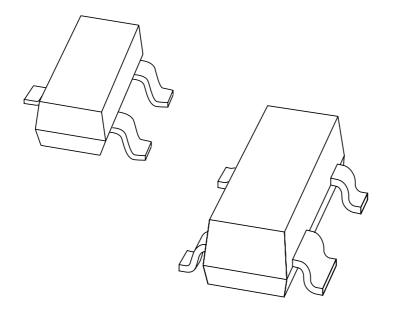
DISCRETE SEMICONDUCTORS

DATA SHEET



BAS70 seriesSchottky barrier (double) diodes

Product specification Supersedes data of 1999 Jun 01 2001 Oct 11





Schottky barrier (double) diodes

BAS70 series

FEATURES

- · Low forward current
- · High breakdown voltage
- · Guard ring protected
- · Small plastic SMD package
- Low diode capacitance.

APPLICATIONS

- Ultra high-speed switching
- · Voltage clamping
- · Protection circuits.

DESCRIPTION

Planar Schottky barrier diodes with an integrated guard ring for stress protection. Single diodes and double diodes with different pinning are available.

The diodes BAS70, BAS70-04, BAS70-05 and BAS70-06 are encapsulated in a SOT23 small plastic SMD package. The BAS70-07 is encapsulated in a SOT143B small plastic SMD package.

MARKING

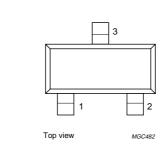
TYPE NUMBER	MARKING CODE ⁽¹⁾
BAS70	73*
BAS70-04	74*
BAS70-05	75*
BAS70-06	76*
BAS70-07	77*

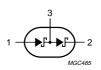
Note

- 1. * = p: Made in Hong Kong.
 - * = t: Made in Malaysia.
 - * = W: Made in China.

PINNING

	DESCRIPTION							
PIN		SOT143B						
	BAS70 (see Fig.1b)	BAS70-04 (see Fig.1c)	BAS70-05 (see Fig.1d)	BAS70-06 (see Fig.1e)	BAS70-07 (see Fig.2)			
1	a ₁	a ₁	a ₁	k ₁	k ₁			
2	n.c.	k ₂	a ₂	k ₂	k ₂			
3	k ₁	k ₁ , a ₂	k ₁ , k ₂	a ₁ , a ₂	a ₂			
4	_	_	_	_	a ₁			



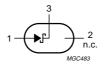


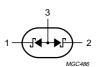
c. BAS70-04



a. Simplified outline SOT23.







b. BAS70 single diode.

e. BAS70-06.

Fig.1 Simplified outline (SOT23) and symbols.

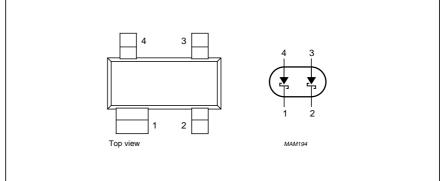


Fig.2 Simplified outline (SOT143B) BAS70-07 and symbol.

Philips Semiconductors Product specification

Schottky barrier (double) diodes

BAS70 series

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	PARAMETER CONDITIONS		MAX.	UNIT			
Per diode								
V _R	continuous reverse voltage		_	70	V			
I _F	continuous forward current		_	70	mA			
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ s}; \ \delta \le 0.5$	_	70	mA			
I _{FSM}	non-repetitive peak forward current	t _p < 10 ms	_	100	mA			
T _{stg}	storage temperature		-65	+150	°C			
Tj	junction temperature		_	150	°C			
T _{amb}	operating ambient temperature		-65	+150	°C			

ELECTRICAL CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT		
Per diode						
V _F	forward voltage	see Fig.3				
		$I_F = 1 \text{ mA}$	410	mV		
		$I_F = 10 \text{ mA}$	750	mV		
		I _F = 15 mA	1	V		
I _R	reverse current	V _R = 50 V; note 1; see Fig.4	100	nA		
		V _R = 70 V; note 1; see Fig.4	10	μΑ		
τ	charge carrier life time (Krakauer method)	I _F = 5 mA	100	ps		
C _d	diode capacitance	f = 1 MHz; V _R = 0; see Fig.6	2	pF		

Note

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	500	K/W

Note

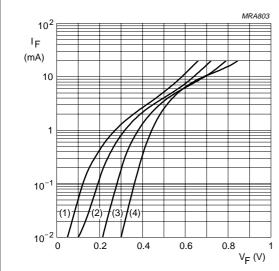
1. Refer to SOT23 or SOT143B standard mounting conditions.

^{1.} Pulse test: $t_p = 300 \ \mu s$; $\delta = 0.02$.

Schottky barrier (double) diodes

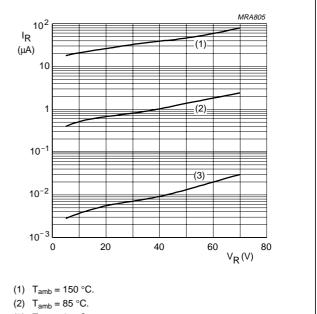
BAS70 series

GRAPHICAL DATA



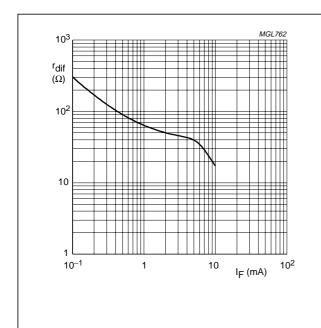
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig.3 Forward current as a function of forward voltage; typical values.



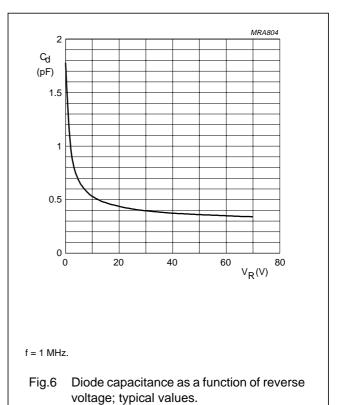
(3) $T_{amb} = 25 \, ^{\circ}C$.

Fig.4 Reverse current as a function of reverse voltage; typical values.



f = 10 kHz.

Fig.5 Differential forward resistance as a function of forward current; typical values.



Philips Semiconductors Product specification

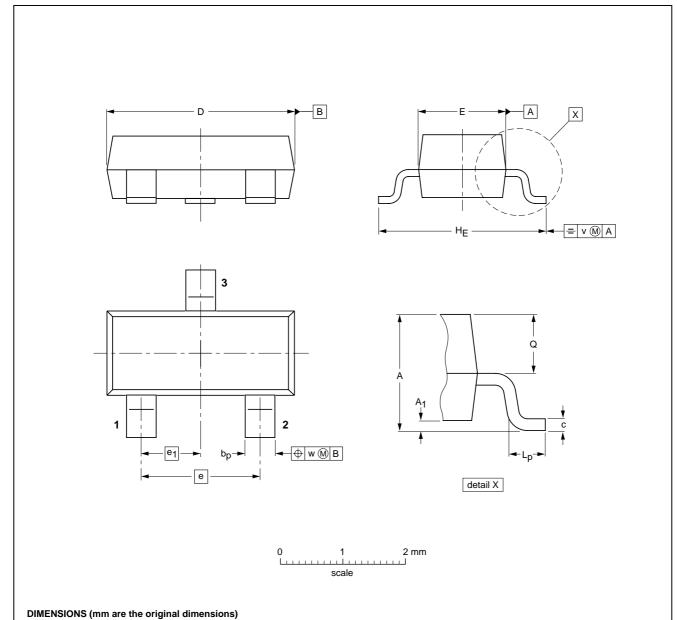
Schottky barrier (double) diodes

BAS70 series

PACKAGE OUTLINES

Plastic surface mounted package; 3 leads

SOT23



OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT23		TO-236AB			97-02-28 99-09-13

 L_{p}

0.45

 H_{E}

Q

0.55

w

0.1

Ε

1.9

2001 Oct 11 5

 $\mathbf{A}_{\mathbf{1}}$

max.

0.48

0.15

1.1

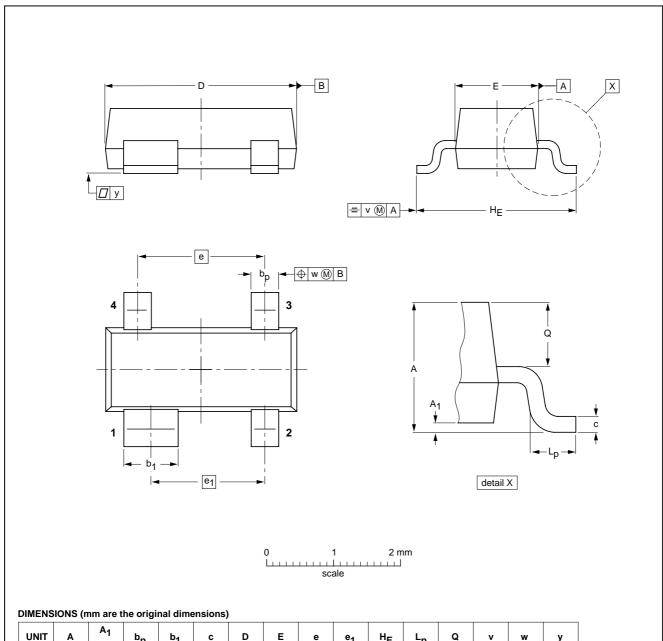
UNIT

Schottky barrier (double) diodes

BAS70 series

Plastic surface mounted package; 4 leads

SOT143B



UNIT	A	A ₁ max	bp	b ₁	С	D	E	е	e ₁	HE	L _p	Q	v	w	у
mm	1.1 0.9	0.1	0.48 0.38	0.88 0.78	0.15 0.09	3.0 2.8	1.4 1.2	1.9	1.7	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1	0.1

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT143B					97-02-28

Philips Semiconductors Product specification

Schottky barrier (double) diodes

BAS70 series

DATA SHEET STATUS

DATA SHEET STATUS(1)	PRODUCT STATUS ⁽²⁾	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

Notes

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- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

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Printed in The Netherlands

613514/06/pp8

Date of release: 2001 Oct 11

Document order number: 9397 750 08761

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